RoHS



Vishay General Semiconductor

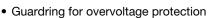
Dual Common Cathode Schottky Rectifier

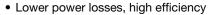


PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 15 A			
V_{RRM}	45 V			
E _{AS}	20 mJ			
I _{FSM}	280 A			
V _F at I _F = 15 A	0.46 V			
T _J max.	150 °C			
Package	TO-220AB			
Diode variations	Common cathode			

FEATURES







Low forward voltage drop

High forward surge capability

• High frequency operation

• Solder dip 260 °C max., 40 s

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-220AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A

whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	M30L45C	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	45	V
Maximum average forward rectified current (fig.1)	total device	I _{F(AV)}	30	А
	per diode		15	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	280	А
Peak repetitive reverse current per diode at t _p = 2 μs, 1 kHz		I _{RRM}	1.0	А
Non-repetitive avalanche energy at 25 °C, I _{AS} = 2 A, per diode		E _{AS}	20	mJ
Operating junction and storage temperature range		T _J , T _{STG}	-65 to +150	°C



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode (1)	V _F	I _F = 8 A	T _A = 25 °C	0.45	-	V	
		I _F = 15 A		0.52	0.60		
		I _F = 30 A		0.67	-		
		I _F = 8 A	T _A = 125 °C	0.36	-		
		I _F = 15 A		0.46	0.50		
		I _F = 30 A		0.63	-		
Reverse current per diode (2)	I _R	_B V _B = 45 V	T _A = 25 °C	210	1000	μΑ	
		IR VR = 45 V	T _A = 125 °C	60	120	mA	
Typical junction capacitance per diode	CJ	4.0 V, 1 MHz		750	-	pF	

Note

⁽²⁾ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL M30L45C		UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	2.0	°C/W	

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
M30L45C-E3/4W	2.07	4W	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

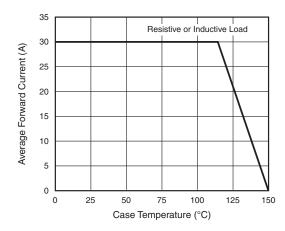


Fig. 1 - Forward Current Derating Curve

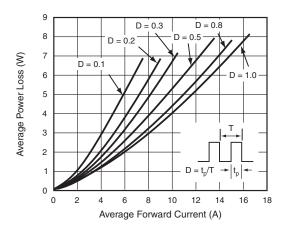


Fig. 2 - Forward Power Loss Characteristics Per Diode

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle



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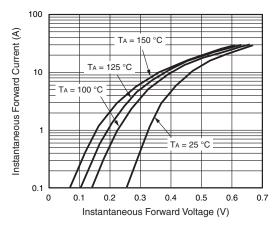


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

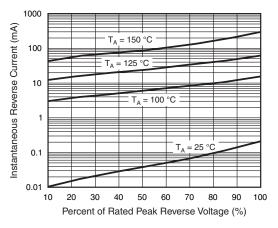


Fig. 4 - Typical Reverse Characteristics Per Diode

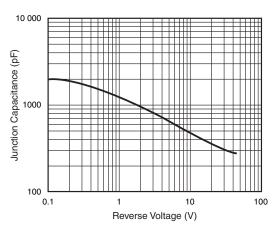


Fig. 5 - Typical Junction Capacitance Per Diode

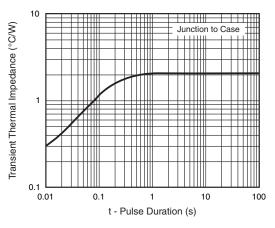
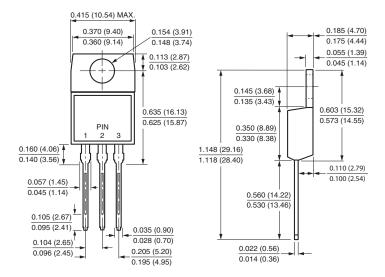


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB





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